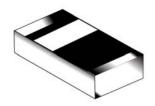
# **Switching Diode**



#### **FEATURES**

- Silicon epitaxial planar diode
- SMD chip pattern, available in various dimension included 1206 & 0603
- Leadfree and RoHS compliance components
- For small signal switching and operating ambient temperature less than 55°C and voltage withstand less than 60V; not suitable for AC switching input as rectified circuit and high reverse voltage location. BAS216 is suitable for those application

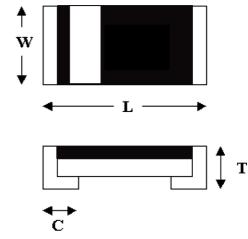
# **MECHANICAL CHARACTERISTICS**

■ Size: 0805

Weight: approx. 6mgMarking: Cathode terminal

# **DIMENSIONS**

Dimension/mm	0805
L	2.0±0.2
W	1.25±0.2
Т	0.85±0.1
С	0.45±0.2



# THERMAL CHARACTERISTICS<sup>1)</sup>

Parameter at T <sub>amb</sub> =25°C <sup>1)</sup>	Symbol	Value	Unit
Forward Power Dissipation	D	200	mW
Power derating above 25°C	P <sub>tot</sub>	1.6	mW/ °C
Junction Temperature	T <sub>i</sub>	150	°C
Thermal Resistance Junction to Ambient air	$R_{\theta JA}$	375	°C/W
Operating& Storage Temperature range	$T_{stg}$	-55 to 150	°C

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.



# MAXIMUM RATING1)

Parameter at T <sub>amb</sub> =25°C <sup>1)</sup>	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	75	V
Average rectified current sin half wave rectification with resistive load	I <sub>F(AV)</sub>	150	mA
Repetitive Peak Forward Current at T <sub>amb</sub> =25°C	$I_{FRM}$	300	mA
Non-Repetitive Surge Forward Current at t<1s and $T_i$ =25°C	${ m I}_{\sf FSM}$	500	mA
at $t \le 8.3$ ms and $T_i = 25$ °C		1000	mA

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.

# **ELECTRICAL CHARACTERISTICS**<sup>1)</sup>

Parameter at T <sub>amb</sub> =25°C <sup>1)</sup>	Symbol	Value	Unit
Forward Voltage at I <sub>F</sub> =10mA	V	1.0 <sub>MAX</sub>	V
at I <sub>F</sub> =100mA	$V_{F}$	1.25 <sub>MAX</sub>	V
Leakage Current at V <sub>R</sub> =20V	т	0.025 <sub>MAX</sub>	uA
Leakage Current at V <sub>R</sub> =75V	$I_{R}$	5 <sub>MAX</sub>	uA
Capacitance at V <sub>R</sub> =0V, f=1MHz	C <sub>tot</sub>	4 <sub>MAX</sub>	pF
Reverse Recovery Time at $I_F = I_R = 10$ mA, $R_L = 100$ $\Omega$	t <sub>rr</sub>	4 <sub>MAX</sub>	ns

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.

#### TYPICAL CHARACTERISTICS

Figure 1. Forward Characteristic

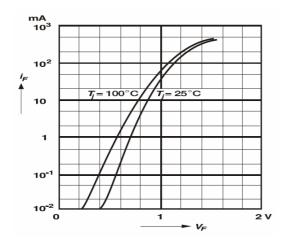


Figure 2. Power De-rating

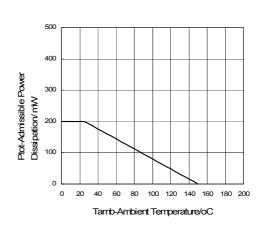


Figure 3. Forward Current De-rating

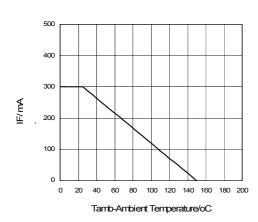
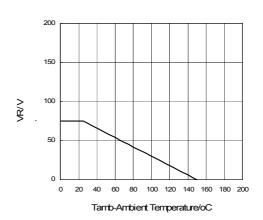


Figure 4. Reverse Voltage De-rating



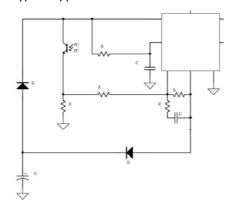
# **TEST CHARACTERISTICS**

Test Item	Test Condition	Requirement
Solderability	Sn bath at 245±5°C for 2±0.5s	>95% area tin covered
Resistance to Soldering Heat	Sn bath at 260±5°C for 10±2s	V <sub>F</sub> ,V <sub>R</sub> & I <sub>R</sub> within spec; no mechanical damage
Humidity Steady State	At 85°C 85%RH for 168hrs	V <sub>F</sub> ,V <sub>R</sub> & I <sub>R</sub> within spec
Continue Forward Operating Life	At 25°C $I_F = 1.1I_F$ for 1000hrs	V <sub>F</sub> ,V <sub>R</sub> & I <sub>R</sub> within spec
Thermal Shock	-55 ±5°C/5min to 150±5°C/5min for 10cycles	V <sub>F</sub> ,V <sub>R</sub> & I <sub>R</sub> within spec
Bending Strength	Bending up to 2mm for 1cycle	V <sub>F</sub> ,V <sub>R</sub> & I <sub>R</sub> within spec; no mechanical damage



#### **APPLICATIONS**

- Function: suit for small signal switching application
- Typical Application circuit:



■ Typical Product field: General application except high reverse voltage location

#### ■ Soldering Condition:

# Soldering Condition & Caution

■ Recommended Soldering Condition (Refer to IPC/JEDEC J-STD-020D 4-1&5.2)

Recommended Profile Condition	Sn-Pb Soldering	Leadfree Soldering	Wave Soldering	
Ramp-up rate (from pre-heat stage)	<3°C/s	<3°C/s	△T<150°C	
Dro host Tomporature & Time	100-150 °C	150-200 °C	100-150 °C	
Pre-heat Temperature & Time	60-120s	60-120s	60-120s	
Coldoring Tomporature & Time	183 °C	217 °C	260±5°C	
Soldering Temperature & Time	60-150s	60-150s	5±2s	
Poak Tomporaturo	230±5°C	245±5°C	260±5°C	
Peak Temperature	<260°C	<260°C	200±3 C	
Time within 5°C of peak temperature	10-20s	20-30s	-	
Ramp-down rate	<6°C/s	<6°C/s	<6°C/s	
Time 25°C to peak temperature	<6min	<8min	-	

Manual Soldering: Approx. 350°C for 3s, avoid solder iron tip direct touch the components body

# Recommended Soldering Profile

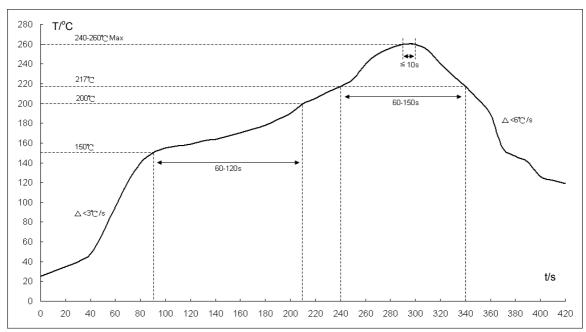


Fig1: Reflow soldering profile for lead-free solder (SnAgCu)

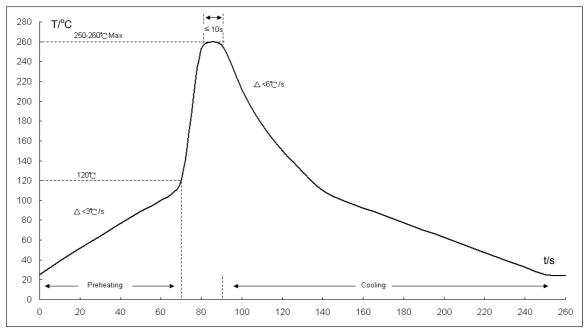
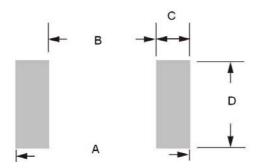


Fig2: Wave soldering profile

- \*1. The recommended profiles are referring to IPC/JEDEC J-STD-020D & IEC-60068-2-58
- \*2. Chip diodes are able to stand maximum soldering temperature up to  $260^{\circ}$ C max for 10s, and the soldering cycles with max 3 times, referring to IEC-60068-2-58

■ Recommended Soldering Footprint:



■ Reflow/Wave Soldering					
Dimension/ mm					
Product Size	Α	В	С	D	
0805	2.6-3.4	1.2	0.7-1.1	1.2-1.4	

■ Storage Condition: Product termination solderability can degrade due to high temperature and humidity or chemical environment. Storage condition must be in an ambient temperature of <40°C and ambient humidity of <75%RH, and free from chemical.

# **ENVIRONMENTAL CHARACTERISTICS**

	Hazardous Substance or Element/ppm					
Product	Pb	Cd	Hg	Cr <sup>6+</sup>	PBB	PBDE
	<1000	<100	<1000	<1000	<1000	<1000
	Halogen Substance/ ppm					
Product	F	Cl	Е	3r	I	Total
	<900	<900	0 <9	900	<900	<1500

# **PACKING METHOD**

Product	Quality/Reel	Reel Size	Tape
	5,000pcs	7"	Paper